



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D TA = +25°C
001/	69mΩ @ V _{GS} = 10V	4.3A
60V	100mΩ @ V _{GS} = 4.5V	3.5A

Description and Applications

This new generation MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Motor controls
- Transformer driving switches
- DC-DC converters
- Power-management functions
- Uninterrupted power supplies

60V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

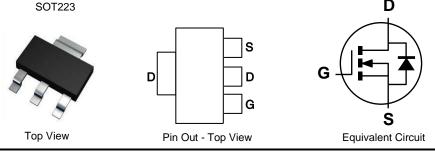
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Fast Switching Speed
- Low On-Resistance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An automotive-compliant part is available under separate datasheet (<u>DMN6069SEQ</u>)

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



Ordering Information (Note 4)

Part Number	Packago	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMN6069SE-13	SOT223	2,500	Tape & Reel	

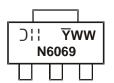
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Note 6) \/co. 10\/	T _A = +25°C T _A = +70°C	ID	4.3 3.3	А
Continuous Drain Current (Note 6) VGS = 10V	T _C = +25°C T _C = +70°C	ID	10 8	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	25	А	
Maximum Body Diode Continuous Current	ls	4.3	А	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Dower Dissipation (Note 6)	T _A = +25°C	De	2.2	W
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.4	
Thermal Resistance, Junction to Ambient (Note 6)		R _{0JA}	58	°C/W
Total Power Dissipation (Note 5)	T _A = +25°C	PD	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	100	°C/W	
Total Power Dissipation (Note 6)	Tc = +25°C	PD	11	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	8.9	°C/W	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					•	
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						·
Gate Threshold Voltage	VGS(TH)	1	_	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Basian	_	47	69	mΩ	$V_{GS} = 10V, I_D = 3A$
Static Dialit-Source Off-Resistance	RDS(ON)		54	100	11122	V _{GS} = 4.5V, I _D = 2.4A
Diode Forward Voltage	V _{SD}		0.8	1.1	V	$V_{GS} = 0V, I_{S} = 2.5A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	825		pF	V _{DS} = 30V, V _{GS} = 0V f = 1MHz
Output Capacitance	Coss	_	40	_		
Reverse Transfer Capacitance	Crss	_	29	_		
Gate Resistance	Rg	_	2.3	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	7.2	_		V _{DS} = 30V, I _D = 12A
Total Gate Charge (V _{GS} = 10V)	Qg	_	16	_	nC	
Gate-Source Charge	Q _{gs}	_	3.2	_	nc	
Gate-Drain Charge	Q _{gd}	_	2.8	_		
Turn-On Delay Time	td(on)		3.8	_		$V_{DD} = 30V, V_{GS} = 10V,$ $R_G = 6\Omega, I_D = 12A$
Turn-On Rise Time	tR	_	6.7	_]	
Turn-Off Delay Time	tD(OFF)		16		ns	
Turn-Off Fall Time	tF		5.3	_]	

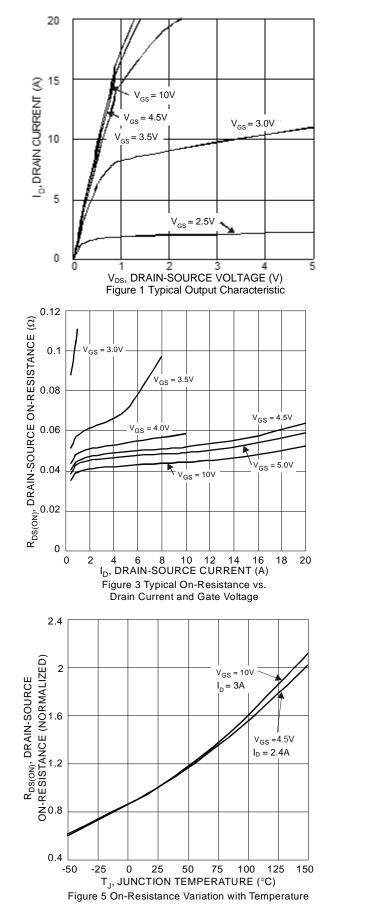
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

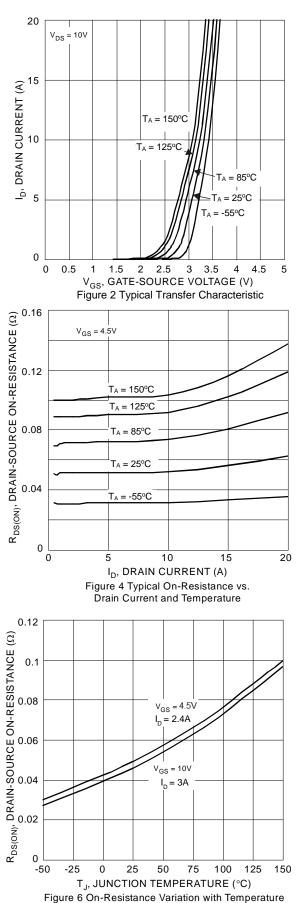
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

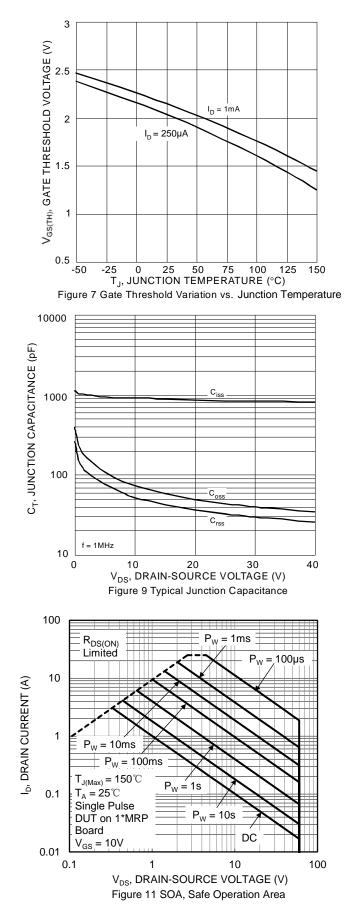


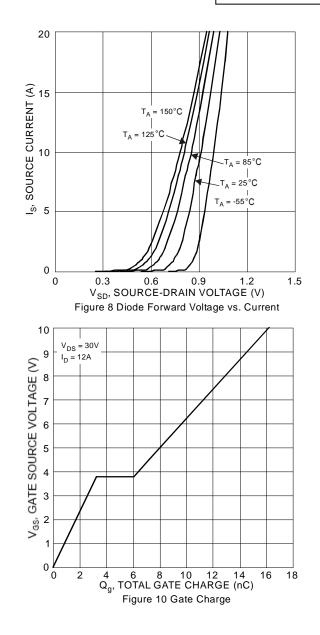




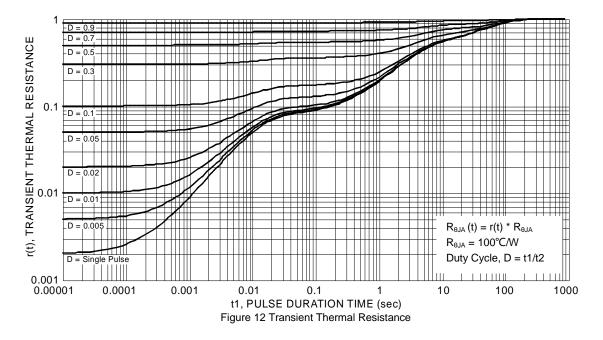
DMN6069SE Datasheet number: DS36474 Rev. 4 - 2 3 of 7 www.diodes.com







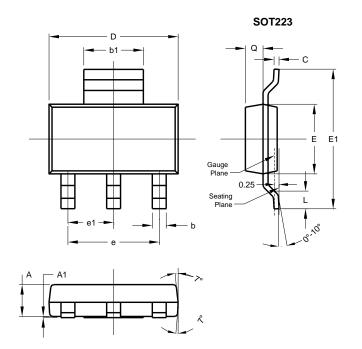






Package Outline Dimensions

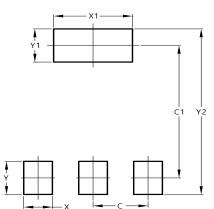
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
E	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm		
С	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Y	1.60		
Y1	1.60		
Y2	8.00		

SOT223



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